A B S T R A C T

SUBSTRATE FOR STRESSED SYSTEMS AND METHOD FOR CRYSTAL GROWTH ON SUCH A SUBSTRATE

The invention provides a support for crystal growth comprising:

- a nucleation layer (2);
- a polycrystal or porous buffer layer (4); and
- a substrate support (6).

Translation of the title and the abstract as they were when originally filed by the Applicant. No account has been taken of any changes that may have been made subsequently by the PCT Authorities acting ex officio, e.g. under PCT Rules 37.2, 38.2, and/or 48.3.